



SGMOP17C-2

1.5MHz, High Voltage, High Precision, Low Noise Rail-to-Rail Output Operational Amplifier

GENERAL DESCRIPTION

The dual SGMOP17C-2 is a rail-to-rail output, low noise and high precision operational amplifier which has low input offset voltage, and bias current. It is guaranteed to operate from 4.5V to 36V single supply.

The rail-to-rail output swing provided by the SGMOP17C-2 makes both high-side and low-side sensing easy. The combination of characteristics makes the SGMOP17C-2 good choice for temperature, position and pressure sensors, medical equipment and strain gauge amplifiers, or any other 4.5V to 36V application requiring precision and long term stability.

The dual SGMOP17C-2 is available in Green SOIC-8 package. It is specified over the extended -40°C to +125°C temperature range.

FEATURES

- **Low Offset Voltage: 120 μ V (MAX)**
- **Rail-to-Rail Output Swing**
- **4.5V to 36V Single Supply Operation**
- **Voltage Gain: 135dB (TYP)**
- **PSRR: 145dB (TYP)**
- **CMRR: 125dB (TYP)**
- **0.1Hz to 10Hz Noise: 1 μ V_{P-P}**
- **56nV/ $\sqrt{\text{Hz}}$ Voltage Noise Density at 1kHz**
- **Gain-Bandwidth Product: 1.5MHz**
- **Low Supply Current:
480 μ A/Amplifier (TYP)**
- **Overload Recovery Time: 3 μ s (TYP)**
- **-40°C to +125°C Operating Temperature Range**
- **Available in Green SOIC-8 Package**

APPLICATIONS

Temperature Measurements
Pressure Sensors
Precision Current Sensing
Electronic Scales
Strain Gauge Amplifiers
Medical Instrumentation
Thermocouple Amplifiers
Handheld Test Equipment

SGMOP17C-2

1.5MHz, High Voltage, High Precision, Low Noise Rail-to-Rail Output Operational Amplifier

PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGMOP17C-2	SOIC-8	-40°C to +125°C	SGMOP17C-2XS8G/TR	SGM OP17C2XS8 XXXXX	Tape and Reel, 2500

NOTE: XXXXX = Date Code and Vendor Code.

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

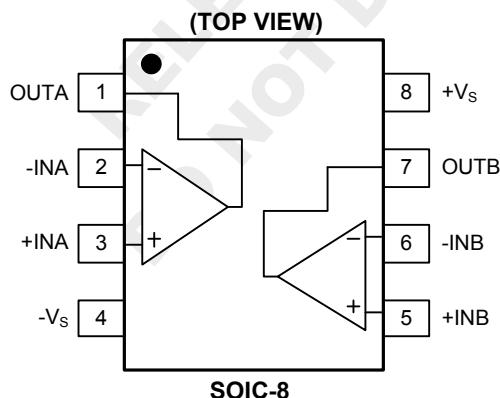
ABSOLUTE MAXIMUM RATINGS

Supply Voltage.....	40V
Input Voltage.....	(-V _S) - 0.3V to (+V _S) + 0.3V
Differential Input Voltage.....	-15V to +15V
Storage Temperature Range	-65°C to +150°C
Junction Temperature.....	+150°C
Lead Temperature (Soldering 10 sec).....	+260°C
ESD Susceptibility	
HBM.....	3000V
MM.....	300V
CDM	1000V

RECOMMENDED OPERATING CONDITIONS

Input Voltage Range	4.5V to 36V
Operating Temperature Range	-40°C to +125°C

PIN CONFIGURATION



OVERSTRESS CAUTION

Stresses beyond those listed may cause permanent damage to the device. Functional operation of the device at these or any other conditions beyond those indicated in the operational section of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

ESD SENSITIVITY CAUTION

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, specification or other related things if necessary without notice at any time.

SGMOP17C-2

1.5MHz, High Voltage, High Precision, Low Noise Rail-to-Rail Output Operational Amplifier

ELECTRICAL CHARACTERISTICS

($V_S = +5V$, $V_{CM} = +2.5V$, $V_O = +2.5V$, $T_A = +25^\circ C$, unless otherwise noted.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
INPUT CHARACTERISTICS					
Input Offset Voltage (V_{OS})		5	120		μV
Input Bias Current (I_B)		100			pA
Input Offset Current (I_{OS})		100			pA
Input Voltage Range		0		3.5	V
Common Mode Rejection Ratio ⁽¹⁾ (CMRR)	$V_{CM} = 0.1V$ to $3.5V$	99	125		dB
	$-40^\circ C \leq T_A \leq +125^\circ C$	97			
Large Signal Voltage Gain (A_{VO})	$R_L = 10k\Omega$, $V_O = 0.3V$ to $4.7V$	110	135		dB
	$-40^\circ C \leq T_A \leq +125^\circ C$	108			
Input Offset Voltage Drift ($\Delta V_{OS}/\Delta T$)		0.3			$\mu V/\text{^\circ C}$
OUTPUT CHARACTERISTICS					
Output Voltage High (V_{OH})	$R_L = 10k\Omega$ to $0V$		75	95	mV
	$-40^\circ C \leq T_A \leq +125^\circ C$			100	
Output Voltage Low (V_{OL})	$R_L = 10k\Omega$ to $5V$		60	75	mV
	$-40^\circ C \leq T_A \leq +125^\circ C$			80	
Short Circuit Limit	I_{SOURCE}	$V_O = 2.5V$, $R_L = 10\Omega$ to $0V$	4.6	8.5	mA
		$-40^\circ C \leq T_A \leq +125^\circ C$	3.5		
	I_{SINK}	$V_O = 2.5V$, $R_L = 10\Omega$ to $5V$	3.9	10	mA
		$-40^\circ C \leq T_A \leq +125^\circ C$	2.9		
POWER SUPPLY					
Power Supply Rejection Ratio ⁽¹⁾ (PSRR)	$V_S = 4.5V$ to $36V$	117	145		dB
	$-40^\circ C \leq T_A \leq +125^\circ C$	115			
Quiescent Current/Amplifier (I_Q)	$V_O = 2.5V$		450	600	μA
	$-40^\circ C \leq T_A \leq +125^\circ C$			790	
DYNAMIC PERFORMANCE					
Gain-Bandwidth Product (GBP)	$A_V = +100$		1.5		MHz
Slew Rate (SR)	$A_V = +1$, $R_L = 10k\Omega$, $2V$ Output Step		1.7		V/ μs
Overload Recovery Time	$A_V = -100$, $R_L = 10k\Omega$, $V_{IN} = 200mV$ (RET to $0V$)		3		μs
Total Harmonic Distortion + Noise (THD+N)	$f = 1kHz$, $A_V = +1$, $V_{OUT} = 2V_{pp}$		0.0006		%
NOISE PERFORMANCE					
Voltage Noise (e_{np-p})	0.1Hz to 10Hz		1		μV_{pp}
Voltage Noise Density (e_n)	$f = 0.1kHz$		56		nV/\sqrt{Hz}
	$f = 1kHz$		56		
	$f = 12kHz$		22		

NOTE 1: PSRR and CMRR are affected by the matching between external gain-setting resistor ratios.

SGMOP17C-2

1.5MHz, High Voltage, High Precision, Low Noise Rail-to-Rail Output Operational Amplifier

ELECTRICAL CHARACTERISTICS (continued)

($V_S = +30V$, $V_{CM} = +15V$, $V_O = +15V$, $T_A = +25^\circ C$, unless otherwise noted.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
INPUT CHARACTERISTICS					
Input Offset Voltage (V_{OS})		4	120		μV
Input Bias Current (I_B)		100			pA
Input Offset Current (I_{OS})		100			pA
Input Voltage Range		0		28.5	V
Common Mode Rejection Ratio ⁽¹⁾ (CMRR)	$V_{CM} = 0.1V$ to 28.5V	112	140		dB
	$-40^\circ C \leq T_A \leq +125^\circ C$	106			
Large Signal Voltage Gain (A_{VO})	$R_L = 10k\Omega$, $V_O = 0.3V$ to 29.7V	119	145		dB
	$-40^\circ C \leq T_A \leq +125^\circ C$	117			
Input Offset Voltage Drift ($\Delta V_{OS}/\Delta T$)		0.3			$\mu V/\text{^\circ C}$
OUTPUT CHARACTERISTICS					
Output Voltage High (V_{OH})	$R_L = 10k\Omega$ to 0V		425	505	mV
	$-40^\circ C \leq T_A \leq +125^\circ C$			555	
Output Voltage Low (V_{OL})	$R_L = 10k\Omega$ to 30V		360	430	mV
	$-40^\circ C \leq T_A \leq +125^\circ C$			455	
Short Circuit Limit	I_{SOURCE}	$V_O = 15V$, $R_L = 10\Omega$ to 0V	23	43	mA
	I_{SINK}	$V_O = 15V$, $R_L = 10\Omega$ to 30V	25	48	mA
POWER SUPPLY					
Power Supply Rejection Ratio ⁽¹⁾ (PSRR)	$V_S = 4.5V$ to 36V	117	145		dB
	$-40^\circ C \leq T_A \leq +125^\circ C$	115			
Quiescent Current/Amplifier (I_Q)	$V_O = 15V$		465	620	μA
	$-40^\circ C \leq T_A \leq +125^\circ C$			800	
DYNAMIC PERFORMANCE					
Gain-Bandwidth Product (GBP)	$A_V = +100$		1.5		MHz
Slew Rate (SR)	$A_V = +1$, $R_L = 10k\Omega$, 2V Output Step		1.8		V/ μs
Overload Recovery Time	$A_V = -100$, $R_L = 10k\Omega$, $V_{IN} = 200mV$ (RET to 0V)		2		μs
Total Harmonic Distortion + Noise (THD+N)	$f = 1kHz$, $A_V = +1$, $V_{OUT} = 2V_{p-p}$		0.0006		%
NOISE PERFORMANCE					
Voltage Noise (e_{npp})	0.1Hz to 10Hz		1		μV_{p-p}
Voltage Noise Density (e_n)	$f = 0.1kHz$		60		nV/\sqrt{Hz}
	$f = 1kHz$		60		
	$f = 12kHz$		22		

NOTE 1: PSRR and CMRR are affected by the matching between external gain-setting resistor ratios.

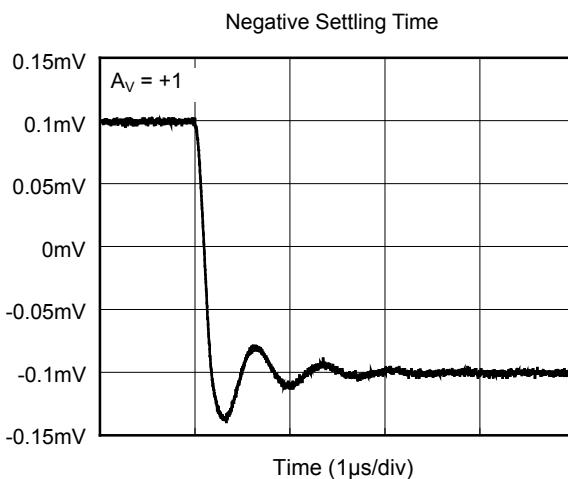
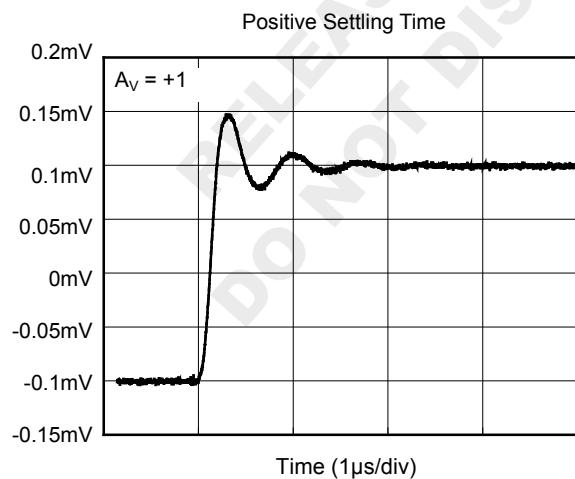
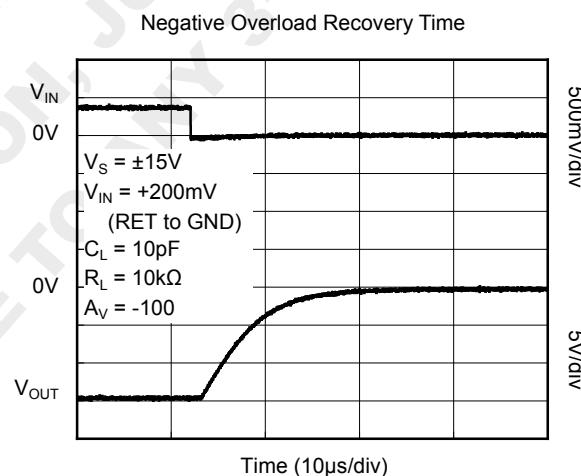
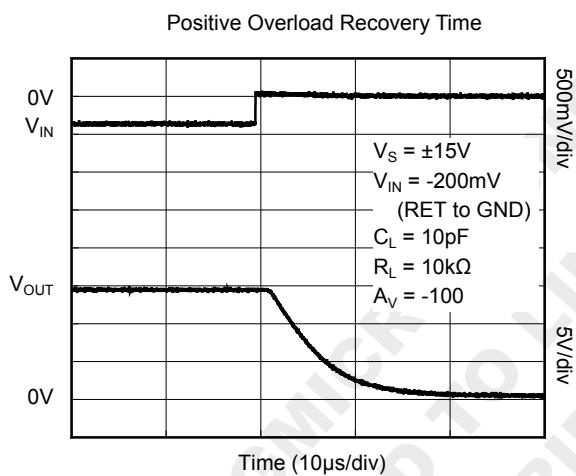
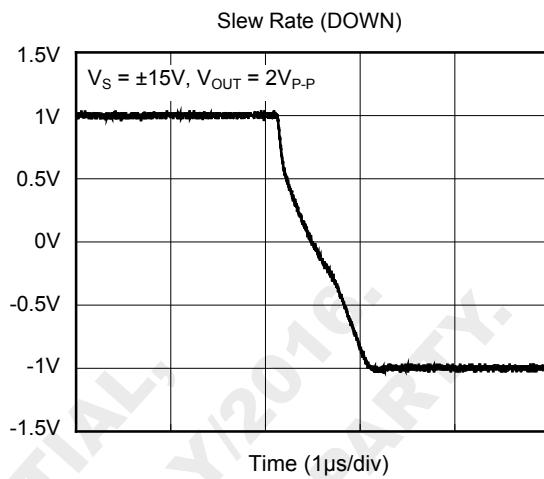
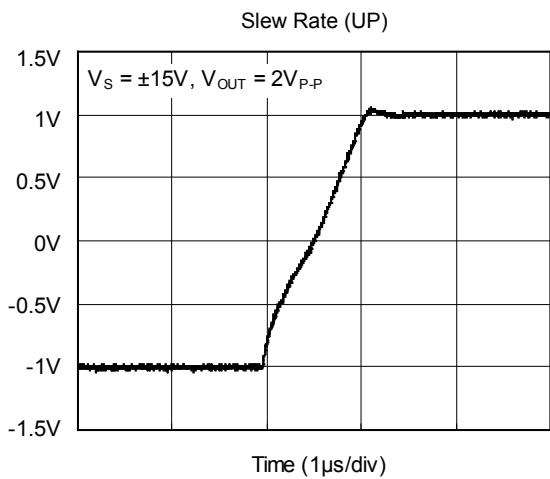
ELECTRICAL CHARACTERISTICS (continued)

(V_S = +36V, V_{CM} = +18V, V_O = +18V, T_A = +25°C, unless otherwise noted.)

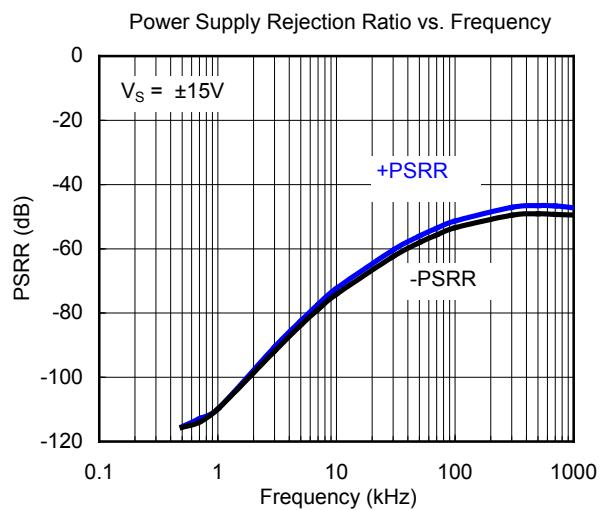
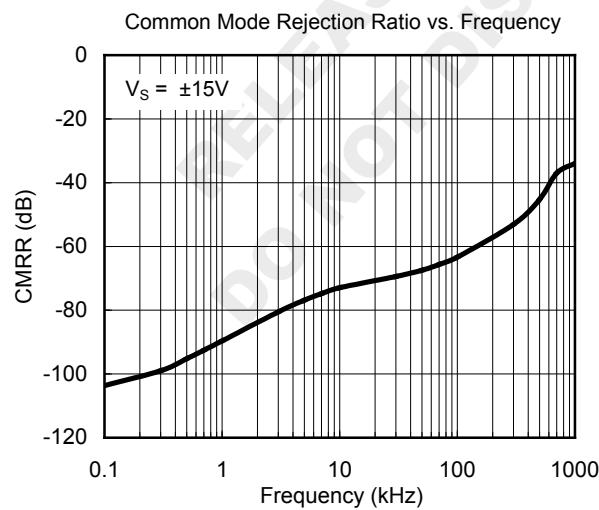
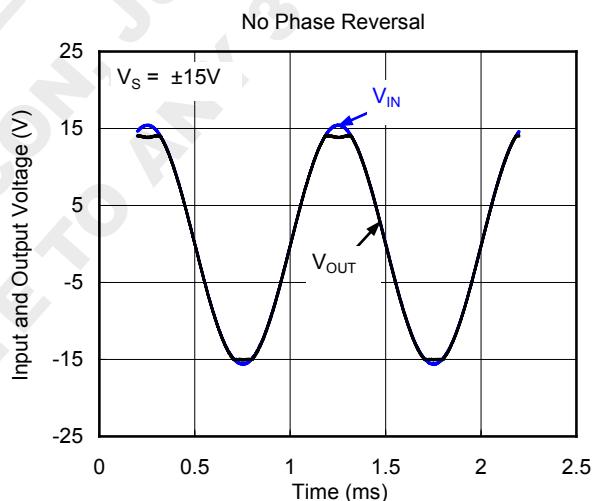
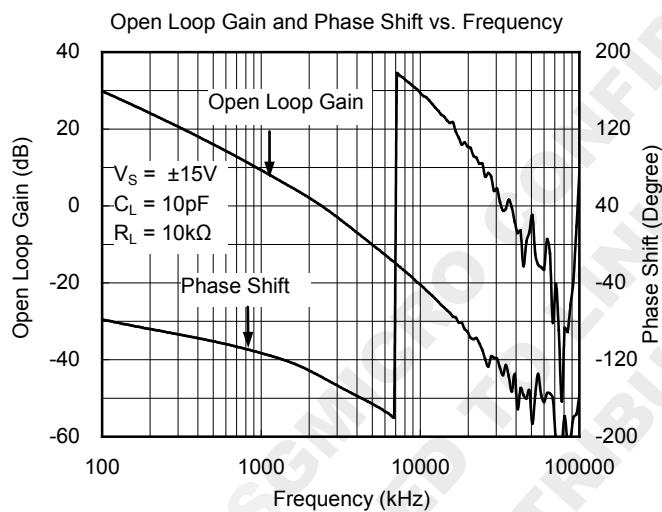
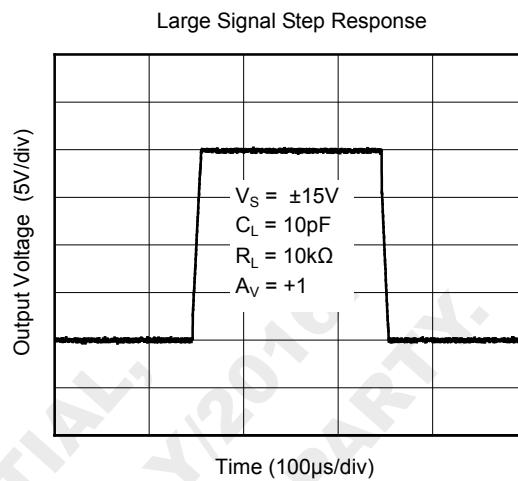
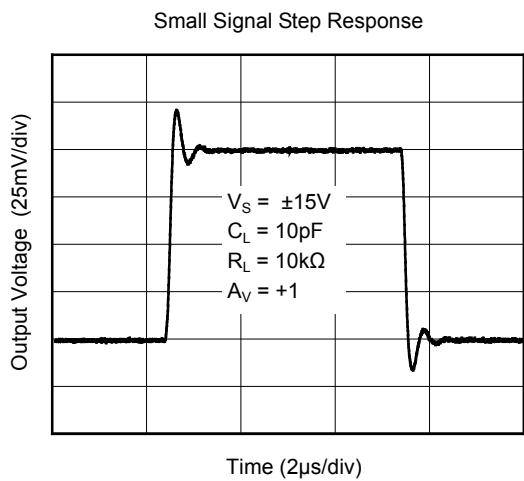
PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
INPUT CHARACTERISTICS					
Input Offset Voltage (V _{OS})		4	120		µV
Input Bias Current (I _B)		100			pA
Input Offset Current (I _{OS})		100			pA
Input Voltage Range		0		28.5	V
Common Mode Rejection Ratio ⁽¹⁾ (CMRR)	V _{CM} = 0.1V to 34.5V	105	130		dB
	-40°C ≤ T _A ≤ +125°C	96			
Large Signal Voltage Gain (A _{VO})	R _L = 10kΩ, V _O = 0.3V to 35.7V	116	150		dB
	-40°C ≤ T _A ≤ +125°C	114			
Input Offset Voltage Drift (ΔV _{OS} /ΔT)		0.3			µV/°C
OUTPUT CHARACTERISTICS					
Output Voltage High (V _{OH})	R _L = 10kΩ to 0V		515	610	mV
	-40°C ≤ T _A ≤ +125°C			675	
Output Voltage Low (V _{OL})	R _L = 10kΩ to 36V		435	515	mV
	-40°C ≤ T _A ≤ +125°C			545	
Short Circuit Limit	I _{SOURCE}	V _O = 15V, R _L = 10Ω to 0V	25	47	mA
	I _{SINK}	V _O = 15V, R _L = 10Ω to 36V	26	51	mA
POWER SUPPLY					
Power Supply Rejection Ratio ⁽¹⁾ (PSRR)	V _S = 4.5V to 36V	117	145		dB
	-40°C ≤ T _A ≤ +125°C	115			
Quiescent Current/Amplifier (I _Q)	V _O = 18V		480	640	µA
	-40°C ≤ T _A ≤ +125°C			820	
DYNAMIC PERFORMANCE					
Gain-Bandwidth Product (GBP)	A _V = +100		1.5		MHz
Slew Rate (SR)	A _V = +1, R _L = 10kΩ, 2V Output Step		1.7		V/µs
Overload Recovery Time	A _V = -100, R _L = 10kΩ, V _{IN} = 200mV (RET to 0V)		2		µs
Total Harmonic Distortion + Noise (THD+N)	f = 1kHz, A _V = +1, V _{OUT} = 2V _{P-P}		0.0006		%
NOISE PERFORMANCE					
Voltage Noise (e _{npp})	0.1Hz to 10Hz		1		µV _{P-P}
Voltage Noise Density (e _n)	f = 0.1kHz		60		nV/√Hz
	f = 1kHz		60		
	f = 12kHz		22		

NOTE 1: PSRR and CMRR are affected by the matching between external gain-setting resistor ratios.

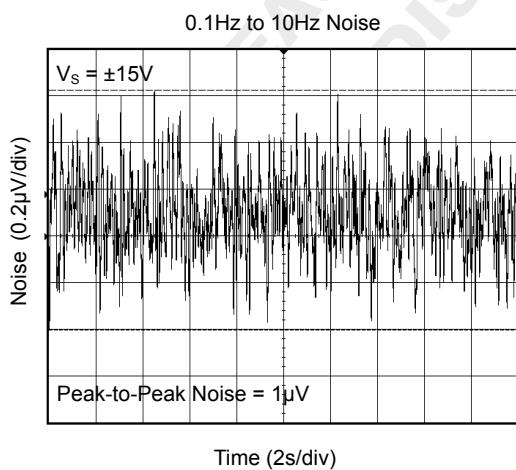
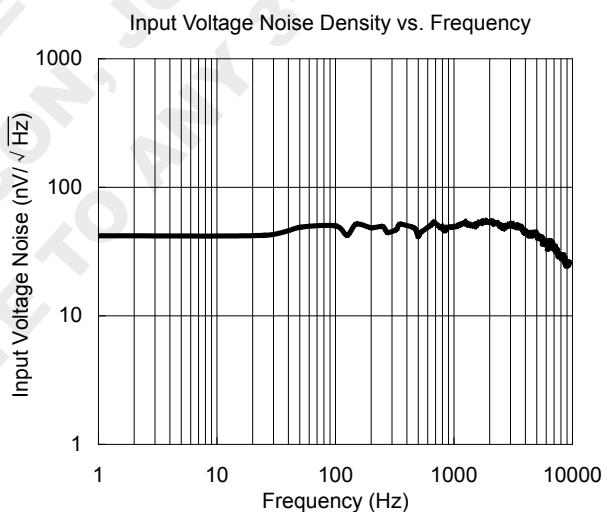
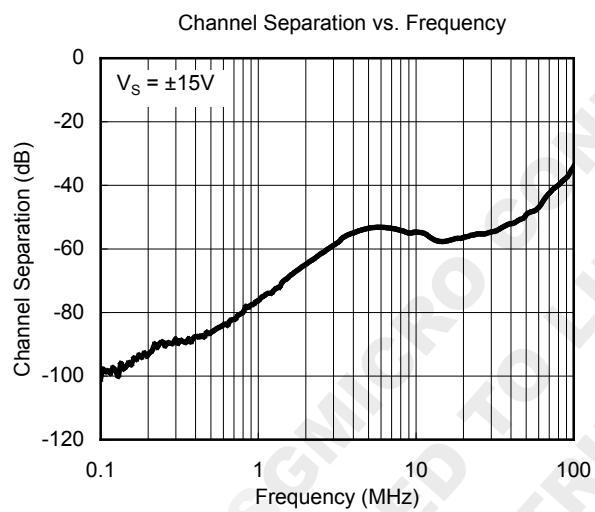
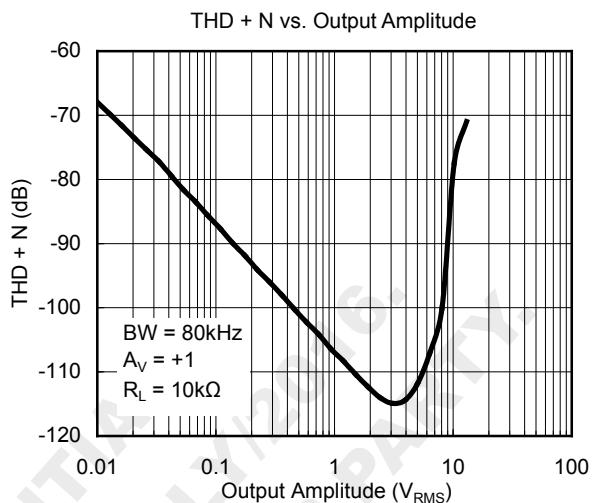
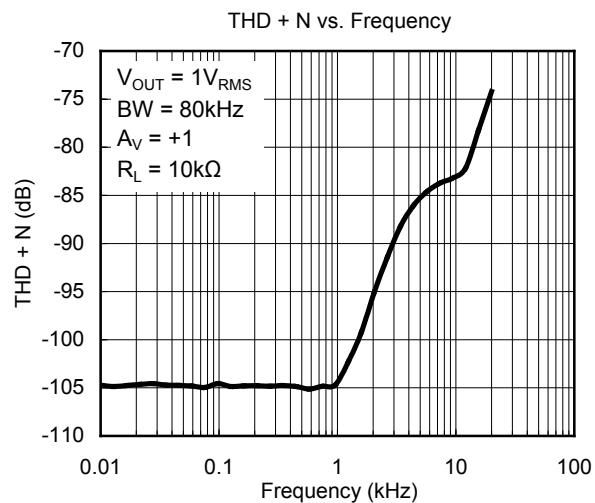
TYPICAL PERFORMANCE CHARACTERISTICS



TYPICAL PERFORMANCE CHARACTERISTICS (continued)



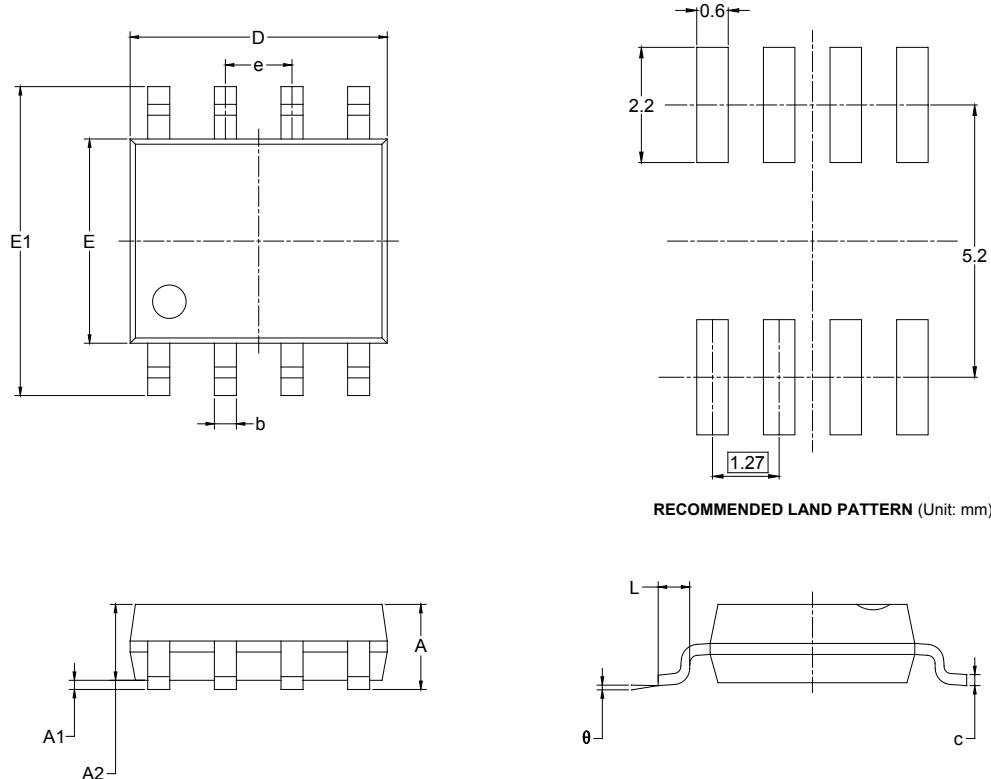
TYPICAL PERFORMANCE CHARACTERISTICS (continued)



PACKAGE INFORMATION

PACKAGE OUTLINE DIMENSIONS

SOIC-8

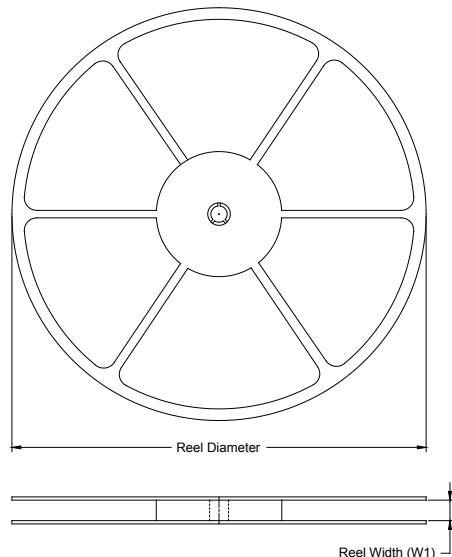


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.27 BSC		0.050 BSC	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

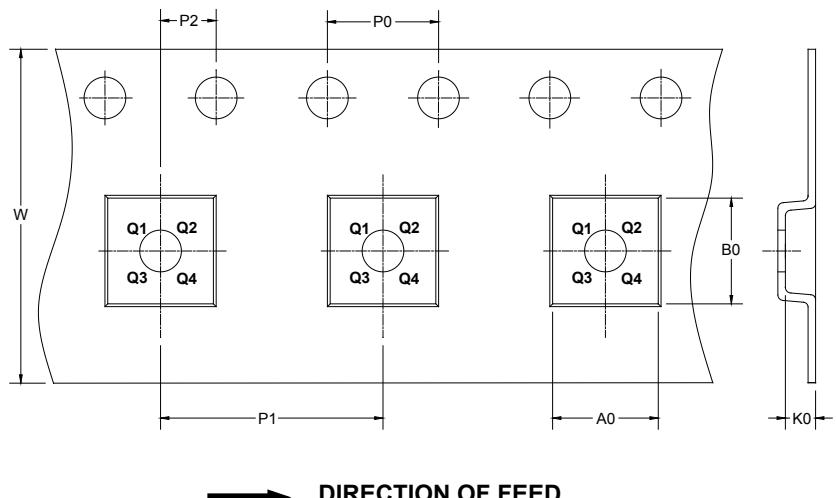
PACKAGE INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



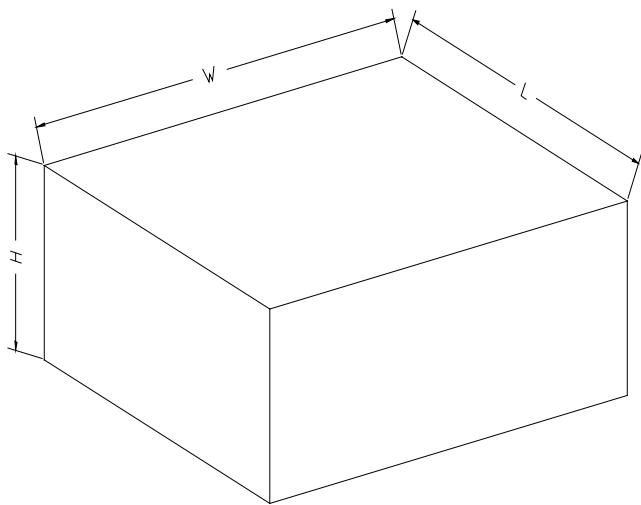
NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOIC-8	13"	12.4	6.4	5.4	2.1	4.0	8.0	2.0	12.0	Q1

PACKAGE INFORMATION

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
13"	386	280	370	5

DD0002